

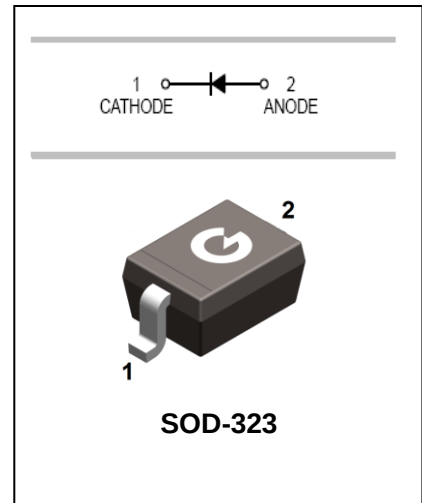
General purpose PIN Diode

TBAP50-03

FEATURES

- Low diode capacitance
- Low diode forward resistance
- Halogen free
- Qualified to AEC-Q101 standards for high reliability
- General purpose PIN diode in a SOD-323 small plastic SMD package

HF



APPLICATIONS

- General RF application

ORDERING INFORMATION

Type No.	Marking	Package Code
TBAP50-03	A81	SOD-323

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Limits	Unit
Continuous reverse voltage	V_R	50	V
Continuous forward current	I_F	50	mA
Forward Surge@8.3ms	I_{FSM}	1.5	A
Power Dissipation	P_D	500	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	250	°C/W
Junction temperature	T_J	-55 to +150	°C
Storage temperature	T_{STG}	-65 to +150	°C

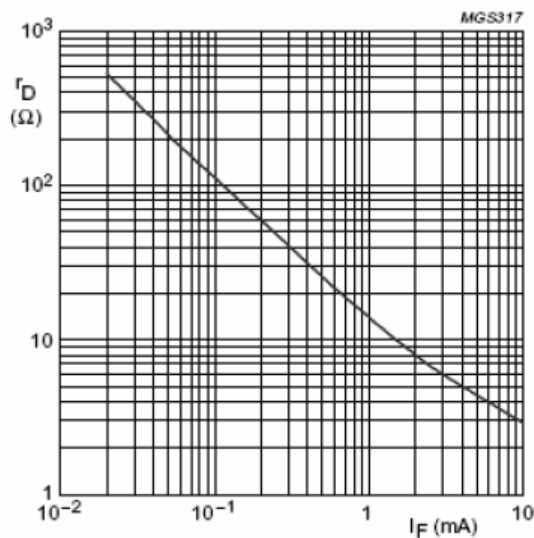
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ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

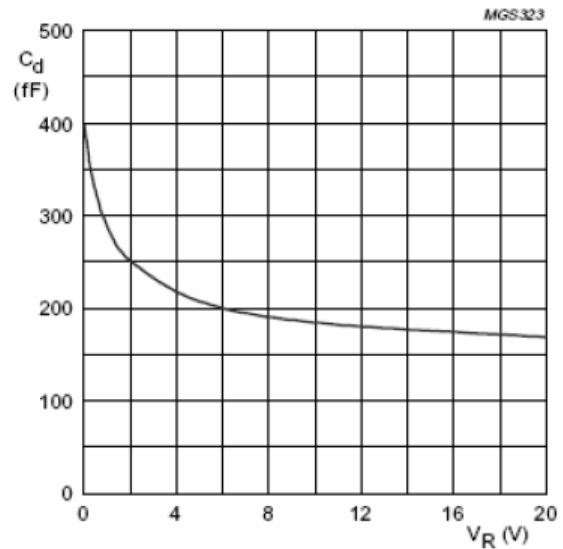
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Continuous reverse voltage	V_R	50			V	$I_R=10\mu\text{A}$
Forward voltage	V_F		0.95	1.1	V	$I_F=50\text{mA}$
Reverse current	I_R			100	nA	$V_R=50\text{V}$
Diode capacitance	C_{d1}		0.4		pF	$V_R=0\text{V}, f=1\text{MHz}$
	C_{d2}		0.3	0.55	pF	$V_R=1\text{V}, f=1\text{MHz}$
	C_{d3}		0.2	0.35	pF	$V_R=5\text{V}, f=1\text{MHz}$
Diode forward resistance	r_D		25	40	Ω	$I_F=0.5\text{mA}, f=100\text{MHz}$
	r_D		14	25	Ω	$I_F=1\text{mA}, f=100\text{MHz}$
	r_D		3	5	Ω	$I_F=10\text{mA}, f=100\text{MHz}$

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



$f = 100\text{ MHz}; T_J = 25^\circ\text{C}.$

Fig.1 Forward resistance as a function of forward current; typical values.

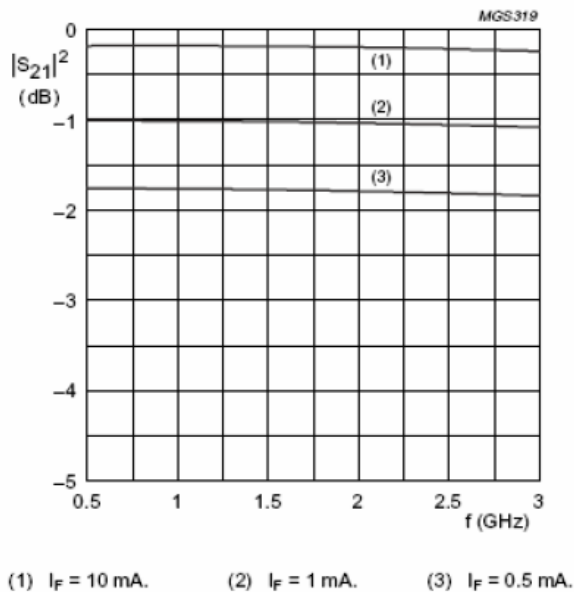


$f = 1\text{ MHz}; T_J = 25^\circ\text{C}.$

Fig.2 Diode capacitance as a function of reverse voltage; typical values.

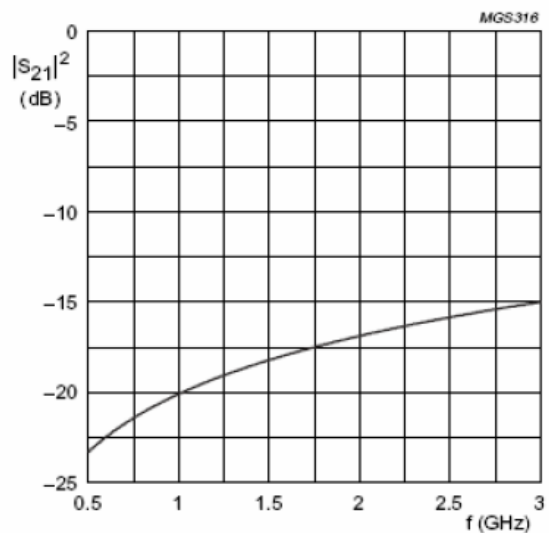
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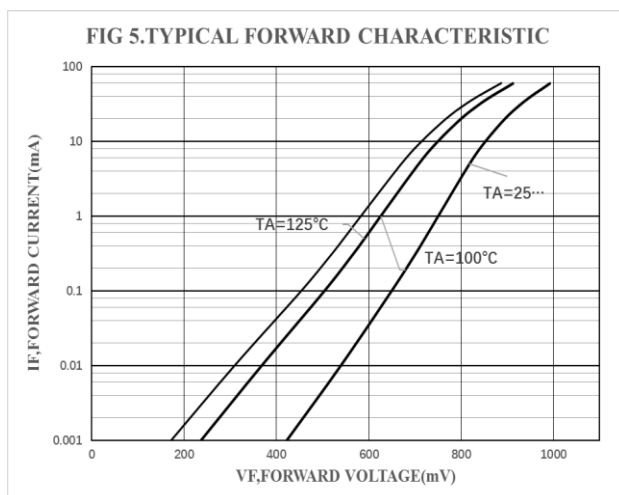
Diode inserted in series with a 50Ω stripline circuit and biased via the analyzer Tee network.
 $T_{amb} = 25^\circ\text{C}$.

Fig.3 Insertion loss ($|S_{21}|^2$) of the diode as a function of frequency; typical values.



Diode zero biased and inserted in series with a 50Ω stripline circuit.
 $T_{amb} = 25^\circ\text{C}$.

Fig.4 Isolation ($|S_{21}|^2$) of the diode as a function of frequency; typical values.



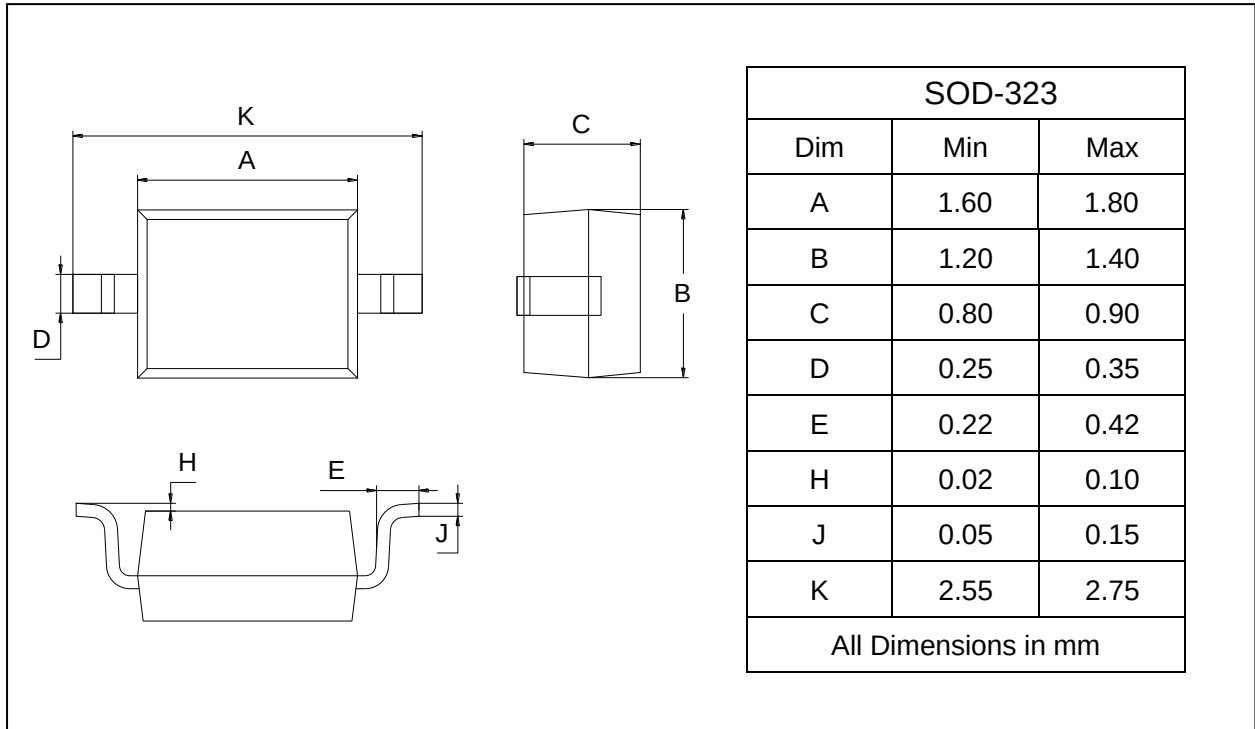
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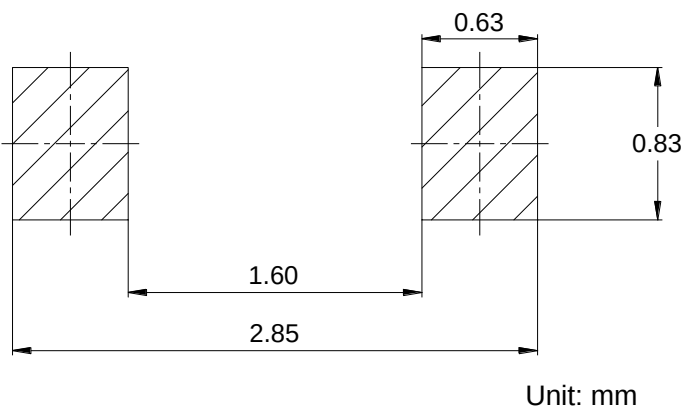
PACKAGE OUTLINE

Plastic surface mounted package

SOD-323



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
TBAP50-03	SOD-323	3000 pcs / Tape & Reel